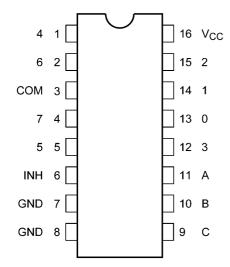
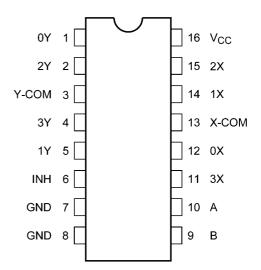


## 5. Pin Assignment

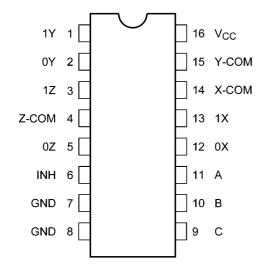
### 74VHC4051AFT



#### 74VHC4052AFT

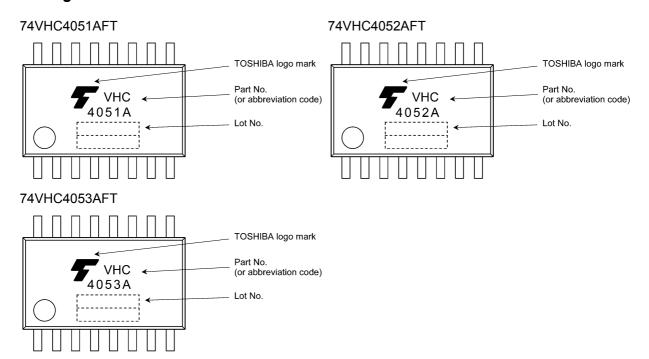


#### 74VHC4053AFT





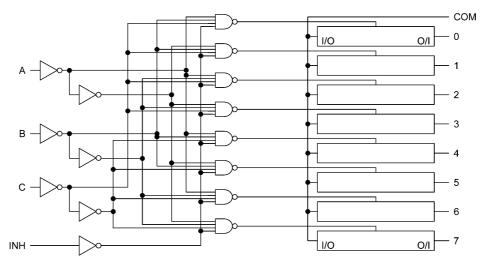
## 6. Marking



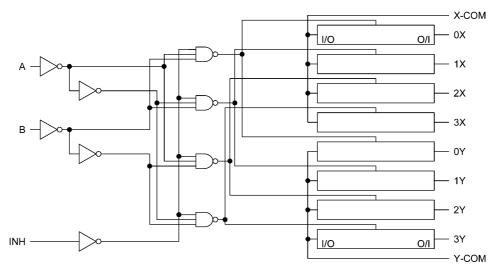


## 7. System Diagram

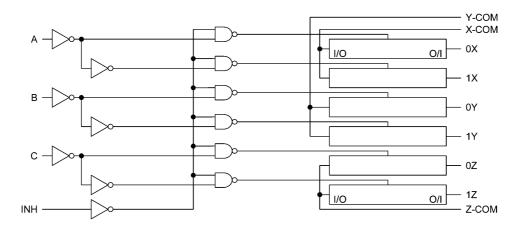
### 74VHC4051AFT



#### 74VHC4052AFT



#### 74VHC4053AFT





#### 8. Truth Table

Input Inhibit	Input C*	Input B	Input A	ON Channel 74VHC4051AFT	ON Channel 74VHC4052AFT	ON Channel 74VHC4053AFT
L	L	L	L	0	0X, 0Y	0X, 0Y, 0Z
L	L	L	Н	1	1X, 1Y	1X, 0Y, 0Z
L	L	Н	L	2	2X, 2Y	0X, 1Y, 0Z
L	L	Н	Н	3	3X, 3Y	1X, 1Y, 0Z
L	Н	L	L	4	_	0X, 0Y, 1Z
L	Н	L	Н	5	_	1X, 0Y, 1Z
L	Н	Н	L	6	_	0X, 1Y, 1Z
L	Н	Н	Н	7	_	1X, 1Y, 1Z
Н	Х	Х	Х	None	None	None

X: Don't care

\*: Except 74VHC4052AFT

## 9. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V <sub>CC</sub>		-0.5 to 7.0	V
Input voltage	V <sub>IN</sub>		-0.5 to 7.0	V
Switch I/O voltage	V <sub>I/O</sub>		-0.5 to V <sub>CC</sub> + 0.5	V
Input diode current	I <sub>IK</sub>		-20	mA
I/O diode current	I <sub>I/OK</sub>		±25	mA
Switch through current	I <sub>T</sub>		±25	mA
V <sub>CC</sub> /ground current	I <sub>CC</sub>		±50	mA
Power dissipation	P <sub>D</sub>	(Note 1)	180	mW
Storage temperature	T <sub>stg</sub>		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: 180 mW in the range of  $T_a$  = -40 to 85 °C. From  $T_a$  = 85 to 125 °C a derating factor of -3.25 mW/°C shall be applied until 50 mW.

## 10. Operating Ranges (Note)

Characteristics	Symbol	Test Condition	Rating	Unit
Supply voltage	V <sub>CC</sub>		2.0 to 5.5	V
Input voltage	V <sub>IN</sub>		0 to 5.5	V
Switch I/O voltage	V <sub>S</sub>		0 to V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>		-40 to 125	°C
Input rise and fall times	dt/dv	V <sub>CC</sub> = 2.5 ± 0.2 V	0 to 200	ns/V
		V <sub>CC</sub> = 3.3 ± 0.3 V	0 to 100	
		V <sub>CC</sub> = 5 ± 0.5 V	0 to 20	

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either  $V_{CC}$  or GND.

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### 11. Electrical Characteristics

# 11.1. DC Characteristics (Unless otherwise specified, T<sub>a</sub> = 25 °C)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Min	Тур.	Max	Unit
High-level input voltage	V <sub>IH</sub>	_	2.0	1.5	_	_	V
			3.0	2.0	_	_	
			4.5	3.15	_	_	
			5.5	3.85	_	_	
Low-level input voltage	V <sub>IL</sub>	_	2.0	_	_	0.5	V
			3.0	_	_	0.8	
			4.5	_	_	1.35	
			5.5	_	_	1.65	
ON-resistance	R <sub>ON</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	2.3	_	200	_	Ω
		$V_{I/O} = V_{CC}$ to GND $I_{I/O} = 2 \text{ mA}$	3.0	_	45	86	
			4.5	_	24	37	
		$V_{IN} = V_{IH}$ or $V_{IL}$	2.3	_	28	73	
		$V_{I/O} = V_{CC}$ or GND $I_{I/O} = 2 \text{ mA}$	3.0	_	22	38	
			4.5	_	17	27	
Difference of ON-resistance	$\Delta R_{ON}$	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	2.3	_	10	25	Ω
between switches		$V_{I/O} = V_{CC}$ to GND $I_{I/O} = 2 \text{ mA}$	3.0	_	5	15	
			4.5	_	5	13	
Input/Output leakage current (Switch OFF)	I <sub>OFF</sub>	$V_{OS} = V_{CC}$ or GND $V_{IS} = GND$ to $V_{CC}$ $V_{IN} = V_{IH}$ or $V_{IL}$	5.5	_	_	±0.1	μΑ
Input/Output leakage current (Switch ON, Output OPEN)	I <sub>I/O</sub>	$V_{OS} = V_{CC}$ or GND $V_{IN} = V_{IH}$ or $V_{IL}$	5.5	_	_	±0.1	μА
Control input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5	_	_	±0.1	μА
Quiescent supply current	I <sub>CC</sub>	$V_{IN} = V_{CC}$ or GND	5.5	_	_	2.0	μА





# 11.2. DC Characteristics (Unless otherwise specified, T<sub>a</sub> = -40 to 85 °C)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Min	Max	Unit
High-level input voltage	V <sub>IH</sub>	_	2.0	1.5	_	V
			3.0	2.0	_	
			4.5	3.15	_	
			5.5	3.85	_	
Low-level input voltage	V <sub>IL</sub>	_	2.0	_	0.50	V
			3.0	_	0.8	
			4.5	_	1.35	
			5.5	_	1.65	
ON-resistance	R <sub>ON</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	2.3	_	_	Ω
		$V_{I/O} = V_{CC}$ to GND $I_{I/O} = 2$ mA	3.0	_	108	
			4.5	_	46	
		V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	2.3	_	84	
		V <sub>I/O</sub> = V <sub>CC</sub> or GND	3.0	_	44	
		$I_{I/O} = 2 \text{ mA}$	4.5	_	31	
Difference of ON-resistance	$\Delta R_{ON}$	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	2.3	_	35	Ω
between switches		V <sub>I/O</sub> = V <sub>CC</sub> to GND	3.0	_	20	
		$I_{I/O} = 2 \text{ mA}$	4.5	_	18	
Input/Output leakage current (Switch OFF)	I <sub>OFF</sub>	$V_{OS} = V_{CC}$ or GND $V_{IS} = GND$ to $V_{CC}$ $V_{IN} = V_{IH}$ or $V_{IL}$	5.5	_	±1.0	μА
Input/Output leakage current (Switch ON, Output OPEN)	I <sub>I/O</sub>	$V_{OS} = V_{CC}$ or GND $V_{IN} = V_{IH}$ or $V_{IL}$	5.5	_	±1.0	μА
Control input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5		±1.0	μА
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5	_	20.0	μА

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# 11.3. DC Characteristics (Unless otherwise specified, T<sub>a</sub> = -40 to 125 °C)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Min	Max	Unit
High-level input voltage	V <sub>IH</sub>	_	2.0	1.5	_	V
			3.0	2.0	_	
			4.5	3.15	_	]
			5.5	3.85	_	
Low-level input voltage	V <sub>IL</sub>	_	2.0	_	0.5	٧
			3.0	_	0.8	]
			4.5	_	1.35	
			5.5	_	1.65	
ON-resistance	R <sub>ON</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	2.3	_	_	Ω
		$V_{I/O} = V_{CC}$ to GND $I_{I/O} = 2$ mA	3.0	_	125	
		11/0 - 2 11/A	4.5	_	54	
		V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	2.3	_	105	1
		V <sub>I/O</sub> = V <sub>CC</sub> or GND	3.0	_	55	1
		$I_{I/O} = 2 \text{ mA}$	4.5	_	39	
Difference of ON-resistance	$\Delta R_{ON}$	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	2.3	_	45	Ω
between switches		V <sub>I/O</sub> = V <sub>CC</sub> to GND	3.0	_	25	1
		$I_{I/O} = 2 \text{ mA}$	4.5	_	23	
Input/Output leakage current (Switch OFF)	I <sub>OFF</sub>	$V_{OS} = V_{CC}$ or GND $V_{IS} = GND$ to $V_{CC}$ $V_{IN} = V_{IH}$ or $V_{IL}$	5.5	_	±4.0	μА
Input/Output leakage current (Switch ON, Output OPEN)	I <sub>I/O</sub>	$V_{OS} = V_{CC}$ or GND $V_{IN} = V_{IH}$ or $V_{IL}$	5.5	_	±4.0	μА
Control input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5		±2.0	μА
Quiescent supply current	Icc	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5	_	40.0	μА





# 11.4. AC Characteristics (Unless otherwise specified, $T_a$ = 25 °C, Input: $t_r$ = $t_f$ = 3 ns)

Characteristics	Part Number	Symbol	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Тур.	Max	Unit
Phase difference between		Φι/Ο		$2.5 \pm 0.2$	15	_	1.2	10	ns
input to output					50	_	2.6	12	
				$3.3 \pm 0.3$	15		0.8	6	
					50	_	1.5	9	
				$5.0 \pm 0.5$	15	_	0.3	4	
					50	_	0.6	6	
Output enable time		$t_{PZL}, t_{PZH}$	$R_L = 1 k\Omega$	$2.5 \pm 0.2$	15	_	3.3	15	ns
			Figure 1		50	_	4.2	25	
				$3.3 \pm 0.3$	15	_	2.3	11	
					50	_	3.0	18	
				$5.0 \pm 0.5$	15	_	1.6	7	
					50	_	2.1	12	
Output disable time		$t_{PLZ}, t_{PHZ}$	$R_L = 1 k\Omega$	2.5 ± 0.2	15	_	6	15	ns
			Figure 1		50	_	9.6	25	
				$3.3 \pm 0.3$	15	_	4.5	11	
					50	_	7.2	18	
				$5.0 \pm 0.5$	15	_	3.2	7	
					50	_	5.1	12	
Control input capacitance		C <sub>IN</sub>	All types	_		_	2		pF
Common terminal capacitance	74VHC4051AFT	C <sub>IS</sub>	Figure 2	–	_	_	23.4	_	pF
	74VHC4052AFT					_	13.1		
	74VHC4053AFT					_	8.2		
Switch terminal capacitance	74VHC4051AFT	Cos	Figure 2	_	_	_	5.7		pF
	74VHC4052AFT					_	5.6		
	74VHC4053AFT					_	5.6	_	
Feedthrough capacitance	74VHC4051AFT	C <sub>IOS</sub>	Figure 2	_	_	_	0.5	_	pF
	74VHC4052AFT					_	0.5	_	
	74VHC4053AFT					_	0.5	_	
Power dissipation capacitance	74VHC4051AFT	C <sub>PD</sub>	Figure 2	_	_	_	15	_	pF
	74VHC4052AFT		(Note 1)			_	24	_	
	74VHC4053AFT			<u> </u>		_	12	_	

Note 1: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

 $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}$ 



# 11.5. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Max	Unit
Phase difference between input to output	Φι/Ο		$2.5 \pm 0.2$	15	_	16	ns
				50	_	18	
			$3.3 \pm 0.3$	15	_	10	
				50	_	12	
			$5.0 \pm 0.5$	15	_	7	
				50	_	8	
Output enable time	$t_{PZL}, t_{PZH}$	$R_L = 1 k\Omega$	$2.5 \pm 0.2$	15	_	20	ns
		Figure 1		50	_	32	
			$3.3 \pm 0.3$	15	_	15	
				50	-	22	
			5.0 ± 0.5	15	_	10	
				50	_	16	
Output disable time	$t_{PLZ}, t_{PHZ}$	$R_L = 1 k\Omega$	$2.5 \pm 0.2$	15	_	23	ns
		Figure 1		50	_	32	
			$3.3 \pm 0.3$	15	_ 15		
				50	_	22	
			5.0 ± 0.5	15		10	
				50	1	16	
Control input capacitance	C <sub>IN</sub>	_		_	_	10	pF

# 11.6. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 125 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Max	Unit
Phase difference between input to output	Φι/Ο		$2.5 \pm 0.2$	15	_	20	ns
				50	1	22	
			$3.3 \pm 0.3$	15	I	13	
				50	ı	14	
			$5.0 \pm 0.5$	15		9	
				50		9.5	
Output enable time	$t_{PZL}, t_{PZH}$	$R_L = 1 k\Omega$	2.5 ± 0.2	15	ı	23.5	ns
		Figure 1		50		37	
			$3.3 \pm 0.3$	15		18	
				50	_	25	
			$5.0 \pm 0.5$	15		12	
				50		19	
Output disable time	$t_{PLZ}, t_{PHZ}$	$R_L = 1 k\Omega$	2.5 ± 0.2	15	ı	28.5	ns
		Figure 1		50		37	
			$3.3 \pm 0.3$	15		18	
			50	_	25		
			$5.0 \pm 0.5$	15	_	12	
				50		19	
Control input capacitance	C <sub>IN</sub>	_	_	_	_	10	pF

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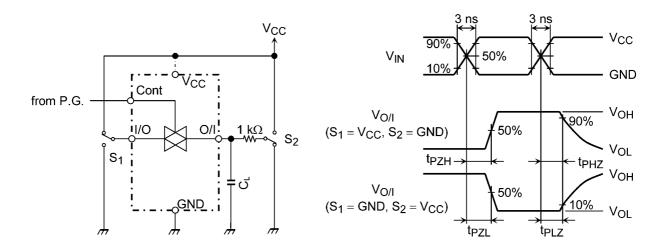
# 11.7. Analog Switch Characteristics (T<sub>a</sub> = 25 °C) (Note)

Characteristics	Part Number	Symbol	Test Condition		V <sub>CC</sub> (V)	Тур.	Unit
Sine Wave Distortion		THD	$R_L = 10 \text{ k}\Omega, C_L = 50 \text{ pF}$	$V_{IN} = 2.0 V_{p-p}$	3.0	0.1	%
			f <sub>IN</sub> = 1 kHz	V <sub>IN</sub> = 4.0 V <sub>p-p</sub>	4.5	0.03	
Maximum frequency	74VHC4051AFT	f <sub>MAX(I/O)</sub>			3.0	150	MHz
response	74VHC4052AFT		Adjust input for 0 dBm. Increase f <sub>IN</sub> frequency until dB			200	
	74VHC4053AFT		meter reads -3 dB.			240	
	74VHC4051AFT	]	$R_L = 50 \Omega$ , $C_L = 10 pF$ , sine		4.5	180	
	74VHC4052AFT	]	wave Figure 3			230	
	74VHC4053AFT		1.9			280	
Feed through attenuation (switch OFF)		FTH	$V_{IN}$ is centered at ( $V_{CC}/2$ ). Adjust input for 0 dBm. $R_L = 600 \ \Omega, \ C_L = 50 \ pF,$		3.0	-45	dB
			f <sub>IN</sub> = 1 MHz, sine wave Figure 4		4.5	-45	
			$V_{IN}$ is centered at ( $V_{CC}/2$ ). Adjust input for 0 dBm. $R_L = 50 \Omega$ , $C_L = 10 pF$ ,		3.0	-65	
			f <sub>IN</sub> = 1 MHz, sine wave Figure 4		4.5	-65	
Crosstalk (control input to signal output)		X <sub>talk</sub>	$R_L = 600 \Omega, C_L = 50 pF,$ $f_{IN} = 1 MHz,$		3.0	60	mV
			square wave ( $t_r = t_f = 6 \text{ ns}$ ) Figure 5		4.5	100	
Crosstalk (between any switches)		X <sub>talk</sub>	V <sub>IN</sub> is centered at (V <sub>CC</sub> /2). Adjust input for 0 dBm.		3.0	-45	dB
			$R_L = 600 \Omega$ , $C_L = 50 pF$ , $f_{IN} = 1 MHz$ , sine wave Figure 6		4.5	-45	

Note: These characteristics are determined by design of devices.



#### 12. AC Test Circuit



Cont : Control Inputs A or B or C or INH (C:Except VHC4052A)

P.G. : Pulse generator

Figure 1 t<sub>PLZ</sub>, t<sub>PHZ</sub>, t<sub>PZL</sub>, t<sub>PZH</sub>

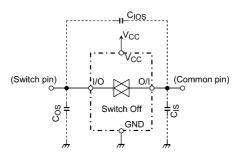


Figure 2 CIOS, CIS, COS

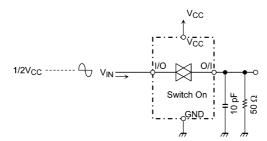


Figure 3 Frequency Response

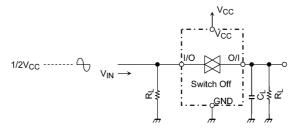
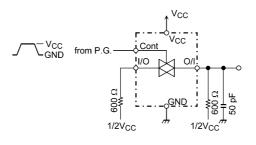


Figure 4 Feedthrough Attenuation

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Cont : Control Inputs A or B or C or INH (C:Except VHC4052A)

P.G. : Pulse generator

Figure 5 Cross Talk (control input to output signal)

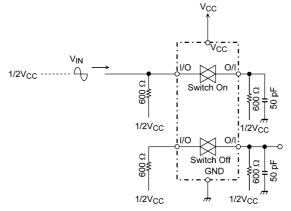


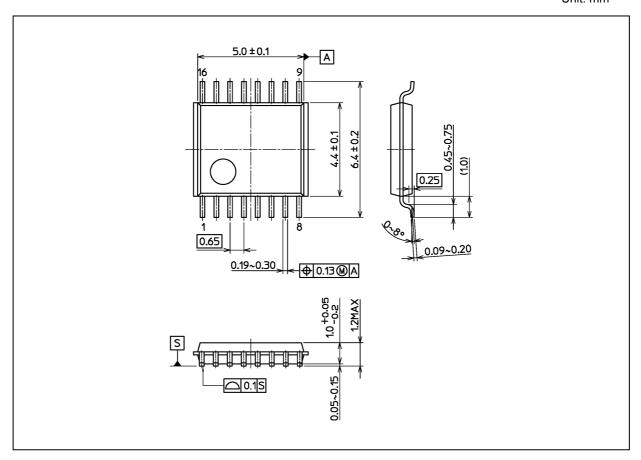
Figure 6 Cross Talk (between any two switches)

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## **Package Dimensions**

Unit: mm



Weight: 0.055 g (typ.)

	Package Name(s)
Nic	kname: TSSOP16B



## 74VHC4051AFT,74VHC4052AFT,74VHC4053AFT

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